

GaAlAs-IR-Lumineszenzdiode (880 nm) und grüne GaP-LED (565 nm) GaAlAs-Infrared-Emitter (880 nm) and green GaP-LED (565 nm)

SFH 7222



Wesentliche Merkmale

- SMT-Gehäuse mit IR-Sender (880 nm) und grünem Sender (565 nm)
- Geeignet für SMT-Bestückung
- Gegurtet lieferbar
- Sender und Empfänger getrennt ansteuerbar
- Geeignet für IR-Reflow Löten

Features

- SMT package with IR emitter (880 nm) and green emitter (565 nm)
- Suitable for SMT assembly
- Available on tape and reel
- Emitter und detector can be controlled separately
- Suitable for IR reflow soldering

Anwendungen

- Kombination von Anzeigeelement mit:
 - Datenübertragung
 - Fernsteuerung
 - Infrarotschnittstelle

Applications

- Combination of display with:
 - data transmission
 - remote control
 - infrared interface

| Typ Type | Bestellnummer Ordering Code | Gehäuse Package |
|---------------------|--|----------------------------|
| SFH 7222 | Q62702-P5095 | SMT Multi TOPLED® |

Grenzwerte**Maximum Ratings**

| Bezeichnung Parameter | Symbol Symbol | Wert Value | | Einheit Unit |
|--|------------------|----------------|----------------|-----------------|
| | | IRED | LED | |
| Betriebstemperatur Operating temperature range | T_{op} | – 40 ... + 100 | – 40 ... + 100 | °C |
| Lagertemperatur Storage temperature range | T_{stg} | – 40 ... + 100 | – 40 ... + 100 | °C |
| Sperrspannung Reverse voltage | V_R | 5 | 5 | V |
| Durchlaßstrom Forward current | I_F (DC) | 100 | 30 | mA |
| Stoßstrom Surge current $t_p \leq 10 \mu\text{s}, D = 0$ | I_{FSM} | 2.5 | 0.5 | A |
| Verlustleistung Total power dissipation | P_{tot} | 180 | 100 | mW |
| Wärmewiderstand Thermal resistance junction/ambient ¹⁾ | $R_{th JA}$ | 450 | 500 | K/W |
| Wärmewiderstand Thermal resistance junction/ambient ²⁾ | $R_{th JA}$ | | 650 | K/W |

¹⁾ nur ein Chip betrieben / only one chip on

²⁾ beide Chips betrieben / both chips on

Hinweis/Notes

Die angegebenen Grenzdaten gelten für einen Chip, wenn nicht anders angegeben.
The stated maximum ratings refer to one chip, unless otherwise specified.

Kennwerte ($T_A = 25^\circ\text{C}$)

Characteristics

| Bezeichnung Parameter | Symbol Symbol | Wert Value | | Einheit Unit |
|---|------------------------------|---|----------------------------------|-----------------|
| | | IRED | LED | |
| Wellenlänge der Strahlung Wavelength of peak emission $I_F = 100 \text{ mA}$ | λ_{peak} | 880 | 565 ($I_F = 10 \text{ mA}$) | nm |
| Dominantwellenlänge Dominant wavelength $I_F = 10 \text{ mA}$ | λ_{dom} | — | 570 | nm |
| Spektrale Bandbreite bei 50% von I_{max} Spectral bandwidth at 50% of I_{max} $I_F = 100 \text{ mA}$ | $\Delta\lambda$ | 80 | 25 ($I_F = 10 \text{ mA}$) | nm |
| Abstrahlwinkel Half angle | φ | ± 60 | ± 60 | Grad deg. |
| Abmessungen der aktiven Chipfläche Dimensions of the active chip area | $L \times B$ $L \times W$ | 0.4×0.4 | 0.25×0.25 | mm^2 |
| Schaltzeiten Switching times 10%/90%, $I_F = 100 \text{ mA}$, $R_L = 50 \Omega$ | t_r, t_f | 500 | 450, 200 | ns |
| Kapazität Capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$ | C_o | 25 | 15 | pF |
| Durchlaßspannung Forward voltage $I_F = 10 \text{ mA}$ $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$ | V_F | — 1.5 (≤ 1.8) 3.0 (≤ 3.8) | 2.0 (≤ 2.6) — — | V |
| Sperrstrom, $V_R = 5 \text{ V}$ Reverse current | I_R | 0.01 (≤ 1) | 0.01 (≤ 10) | μA |
| Gesamtstrahlungsfluß Total radiant flux $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | Φ_e | 23 | — | mW |
| Lichtstärke Luminous intensity $I_F = 2 \text{ mA}$ | I_V | — | 8 (> 4) | mcd |
| Temperaturkoeffizient von I_e bzw. Φ_e Temperature coefficient of I_e or Φ_e $I_F = 100 \text{ mA}$ | TC_I | -0.5 | -0.3 | %/K |

Kennwerte ($T_A = 25^\circ\text{C}$)
Characteristics (cont'd)

| Bezeichnung Parameter | Symbol Symbol | Wert Value | | Einheit Unit |
|---|--------------------------|-----------------------|--|-------------------------|
| | | IRED | LED | |
| Temperaturkoeffizient von V_F Temperature coefficient of V_F $I_F = 100 \text{ mA}$ | TC_V | - 2 | - 1.4 | mV/K |
| Temperaturkoeffizient von λ Temperature coefficient of λ $I_F = 100 \text{ mA}$ | TC_λ | + 0.25 | $0.3 \times \lambda_{\text{peak}}$ $0.07 \times \lambda_{\text{dom}}$ | nm/K |

Strahlstärke I_e der IRED in Achsrichtung

gemessen bei einem Raumwinkel $\Omega = 0.01 \text{ sr}$

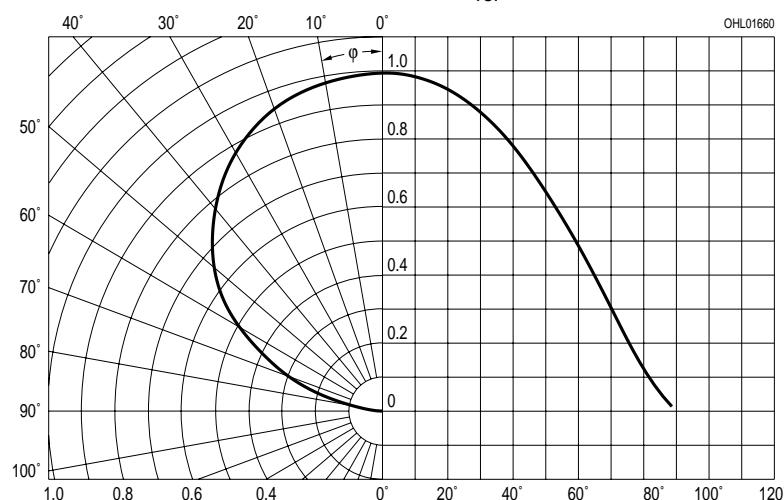
Radiant Intensity I_e of the IRED in Axial Direction

at a solid angle of $\Omega = 0.01 \text{ sr}$

| Bezeichnung Description | Symbol Symbol | Werte Values | Einheit Unit |
|--|--------------------------|-------------------------|-------------------------|
| Strahlstärke Radiant intensity $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | $I_e \text{ min.}$ | ≥ 4 | mW/sr |
| Strahlstärke Radiant intensity $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$ | $I_e \text{ typ.}$ | 48 | mW/sr |

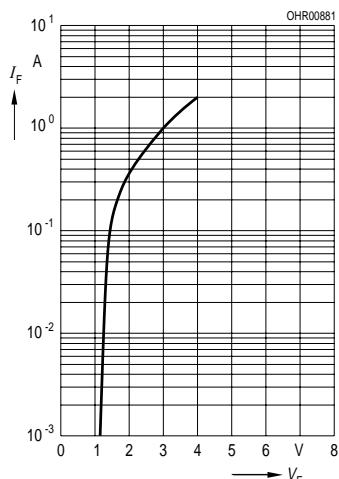
IRED Radiation Characteristics $I_{\text{rel}} = f(\phi)$

LED Directional Characteristics $S_{\text{rel}} = f(\phi)$

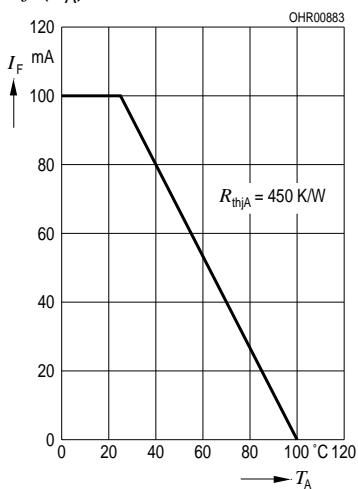


IRED

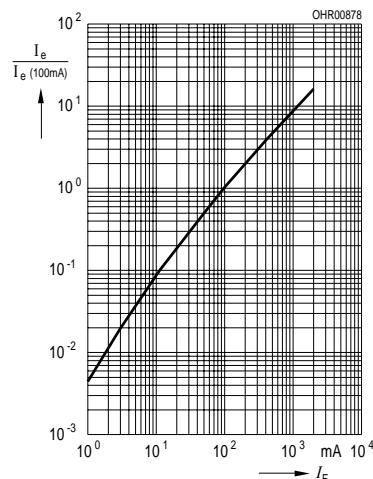
Forward Current $I_F = f(V_F)$
 $T_A = 25^\circ\text{C}$



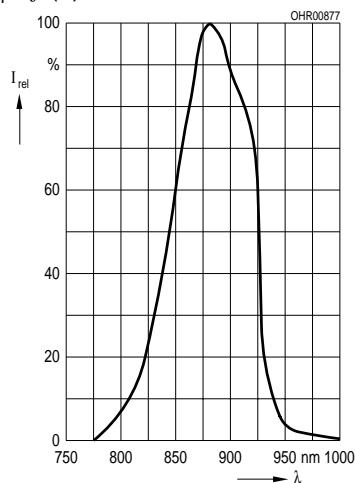
Max. Permissible Forward Current
 $I_F = f(T_A)$



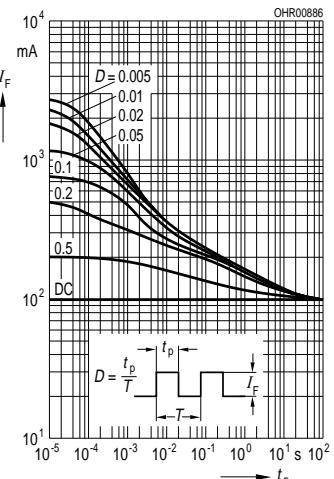
Rel Luminous Intensity
 $I_V / I_{V(10 \text{ mA})} = f(I_F)$
 $T_A = 25^\circ\text{C}$

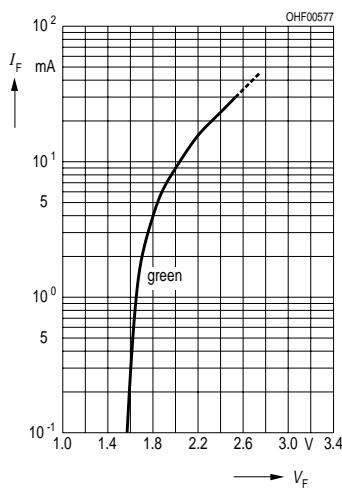
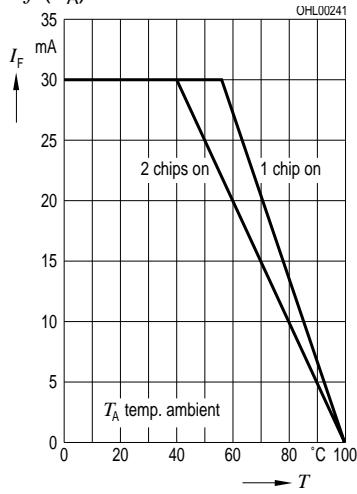
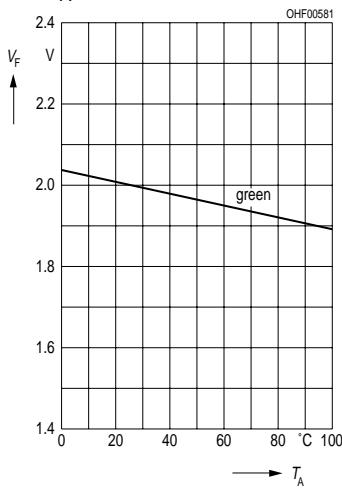
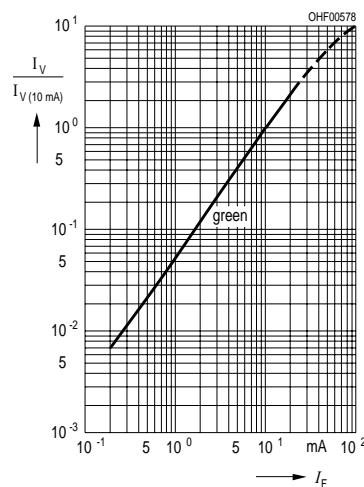
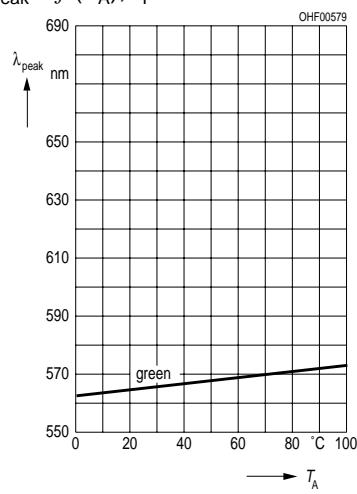
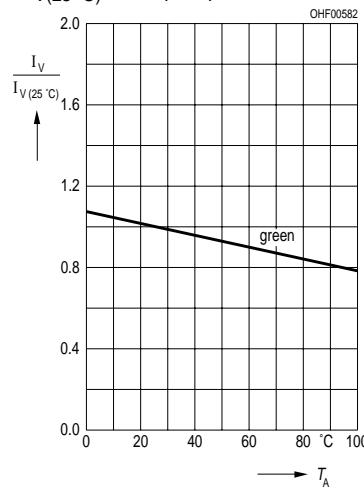
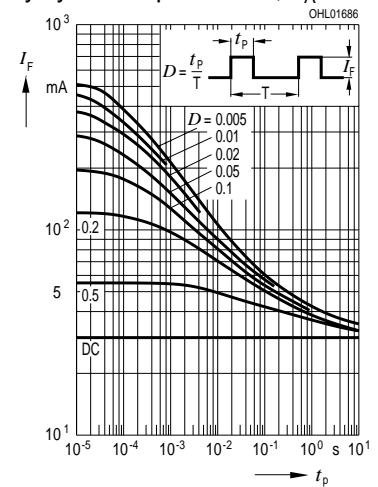
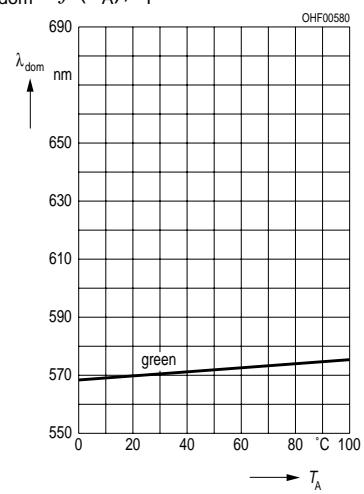


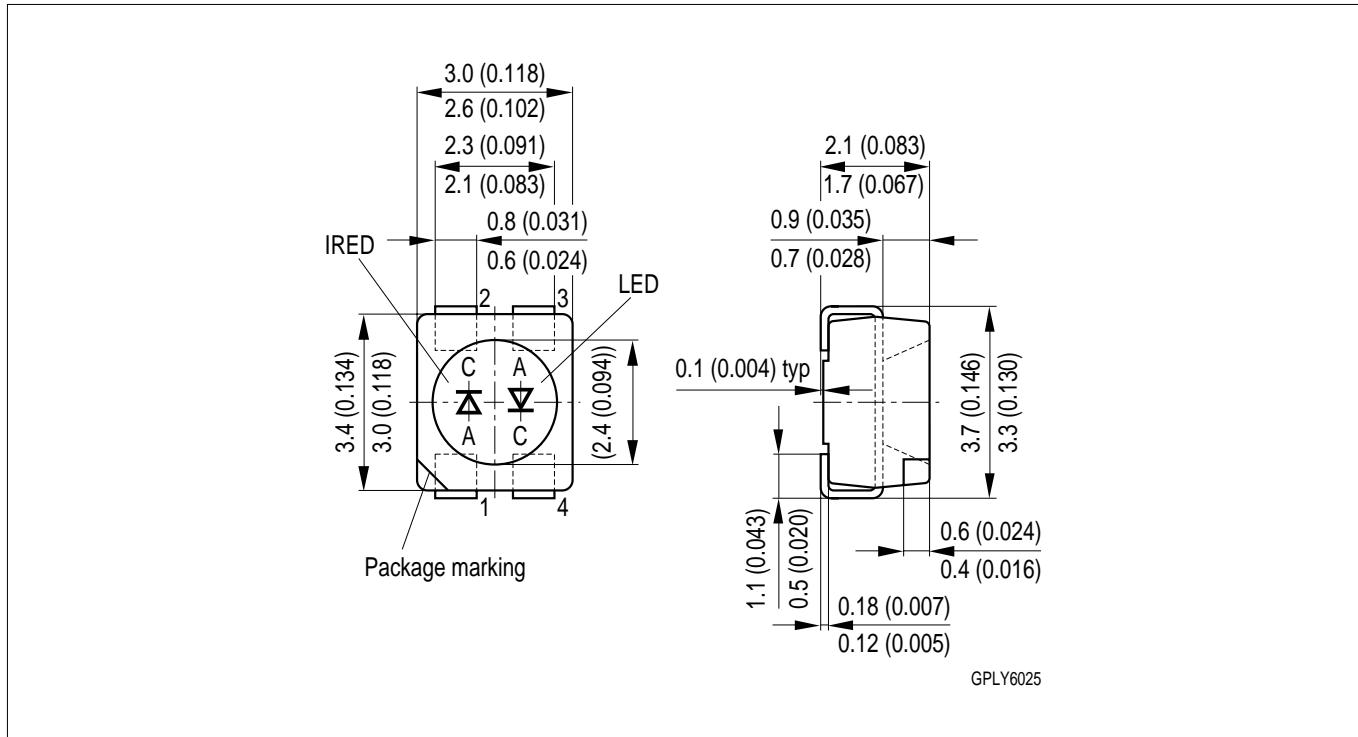
Relative Spectral Emission
 $I_{\text{rel}} = f(\lambda)$



Perm. Pulse Handling Capability
 $I_F = f(t_p)$, Duty cycle $D = \text{parameter}$,
 $T_A = 25^\circ\text{C}$



LED**Forward Current $I_F = f(V_F)$** $T_A = 25^\circ\text{C}$ **Max. Permissible Forward Current** $I_F = f(T_A)$ **Forward Voltage $V_F = f(T_A)$** $I_F = f(T_A)$ **Relative Luminous Intensity** $I_V / I_{V(10 \text{ mA})} = f(I_F), T_A = 25^\circ\text{C}$ **Wavelength at Peak Emission** $\lambda_{\text{peak}} = f(T_A), I_F = 10 \text{ mA}$ **Relative Luminous Intensity** $I_V / I_{V(25^\circ\text{C})} = f(I_F), I_F = 10 \text{ mA}$ **Perm. Pulse Handling Capability** $I_F = f(t_p)$ Duty cycle $D = \text{parameter}, T_A = 25^\circ\text{C}$ **Dominant Wavelength** $\lambda_{\text{dom}} = f(T_A), I_F = 10 \text{ mA}$ 

**Maßzeichnung
Package Outlines**

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).